

# 2.4 GHz 802.11 b/g/n WLAN FRONT-END MODULE

Package Style: QFN, 16-pin, 3mmx3mmx0.5mm

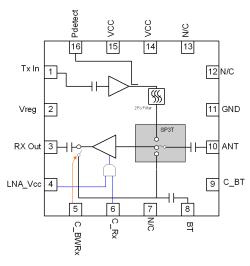


## **Features**

- Integrated 2.4 GHz b/g/n Amplifier, LNA, SP3T Switch, and Power Detector Coupler
- Single Supply Voltage 3.0V to 4.8V
- P<sub>OUT</sub>=20dBm, 11g, 0FDM at <4% EVM, 23dBm 11b Meeting 11b Spectral Mask

## **Applications**

- IEEE802.11b/g/n WLAN
- 2.5 GHz ISM Band Solutions
- Portable Battery-Powered Equipment



Functional Block Diagram

## **Product Description**

The RF5765 provides a complete integrated solution in a single Front End Module (FEM) for WLAN 802.11b/g/n and Bluetooth® systems. The ultra small form factor and integrated matching greatly reduces the number of external components and layout area in the customer application. This simplifies the total Front End solution by reducing the bill of materials, system footprint, and manufacturability cost. The RF5765 integrates a 2.4GHz Power Amplifier (PA), Low Noise Amplifier (LNA), power detector coupler for improved accuracy, and some filtering for harmonic rejection. The RF5765 is capable of receiving WLAN and Bluetooth® simultaneously.

The RF5/65 is capable of receiving WLAN and Bluetooth simultaneously. The device is provided in a 3mmx3mmx0.5mm, 16-pin package. This module meets or exceeds the RF Front End needs of IEEE 802.11b/g/n WLAN RF systems.

### **Ordering Information**

RF5765 2.4GHz 802.11b/g/n WLAN Front-End Module
RF5765PCK-410 Fully Assembled Evaluation Board with 5 piece Sample

Optimum Technology Matching® Applied							
☐ GaAs HBT	☐ SiGe BiCMOS	✓ GaAs pHEMT	☐ GaN HEMT				
☐_GaAs MESFET	☐ Si BiCMOS	☐ Si CMOS	☐ RF MEMS				
✓ InGaP HBT	☐ SiGe HBT	☐ Si BJT	☐ LDMOS				



## **Absolute Maximum Ratings**

Parameter	Rating	Unit
DC Supply Voltage (Continuous with No Damage)	5.4	V
DC Supply Current	500	mA
Full Specification Temp Range (Full Spec. Compliant)	-10 to +70	°C
Extreme Operating (Reduced Performance)	-40 to -10 +70 to +85	°C
Storage Temperature	-40 to +150	°C
Antenna Port Nominal Impedance	50	Ω
Maximum TX Input Power into 50Ω Load for 11b/g/n (No Damage)	0	dBm
Maximum RX Input Power (No Damage)	0	dBm
Moisture Sensitivity	MSL2	



Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

RoHS status based on EU Directive 2002/95/EC (at time of this document revision).

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Davis visata v	Specification					
Parameter	Min. Typ. Max		Max.	Unit	Condition	
2.4 GHz Transmit Parameters	_					
Compliance					IEEE802.11b, IEEE802.11g, FCC CFG 15.247, .205, .209, EN, and JDEC	
Operating Conditions					$\label{eq:VCC} \begin{array}{l} V_{CC}\text{=}3.0\text{V to }4.2\text{V (Spec Compliant); } V_{CC}\text{>}4.2\text{V to }4.8\text{V} \\ \text{(Reduced Performance); } V_{REG}\text{=}3.0\text{V to }3.2\text{V; Switch Control voltage} = 3.0\text{V to }3.6\text{V; Temp} = -10\ ^{\circ}\text{C to }+70\ ^{\circ}\text{C (Spec Compliant); Temp} = -30\ ^{\circ}\text{C to }-10\ ^{\circ}\text{C and }+70\ ^{\circ}\text{C to }+85\ ^{\circ}\text{C (Reduced Performance). Unless noted otherwise.} \end{array}$	
Frequency	2.4		2.5	GHz		
Power Supply	3.0	3.3	4.2	V	Power Amplifier Voltage Supply (V <sub>CC</sub> )	
V <sub>REG</sub> Voltage						
ON	3.0	3.1	3.2	V	PA in "ON" state	
OFF		0.00	0.20	V	PA in "OFF" state	
Output Power						
11g	18	19.5		dBm	54Mbps OFDM 64QAM, V <sub>CC</sub> > 3.0V, Temp=25 °C	
	19	20		dBm	54Mbps OFDM 64QAM, V <sub>CC</sub> > 3.3V, Temp=25 °C	
11b	20	23		dBm	11Mbps CCK signal, BT=0.45, V <sub>CC</sub> >=3.3V, Temp=25 °C	
EVM		3.3	4.0	%	$P_{OUT}(g)$ = Rated Output Power, 54 Mbps OFDM, 50 $\Omega$ , s note 1	
Adjacent Channel Power					P <sub>OUT</sub> (b)=23dBm, 11Mbps CCK signal, V <sub>CC</sub> >=3.3V, senote 4	
ACP1		-36	-33	dBc	+/- 11 MHz Offset from carrier	
ACP2		-56	-51	dBc	+/- 22 MHz Offset from carrier	
Gain	26	30	34.5	dB		
Gain Variation Slope					At rated power and a given supply voltage	
Range	3.0		4.8	V		
V <sub>CC</sub> (Average)			0.5	dB/V		
V <sub>CC</sub> (Instantaneous)			1	dB/V		
Frequency	-0.5		+0.5	dB	2.4GHz to 2.5GHz	
Over Temperature	-1.75		+1.75	dB	V <sub>CC</sub> =3.3V, V <sub>REG</sub> =3.1V, Freq=2.45 GHz	



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Parameter	Min.	Тур.	Max.	Unit	Condition
2.4 GHz Transmit					
Parameters, continued					
Typical Input Power					
11g		-9		dBm	
11b		-5		dBm	
Power Detect					
Power Range	0		23	dBm	
Voltage Range	0.1		1.5	V	
Resistance		10		kΩ	
Capacitance			10	pF	
Sensitivity					
0 <p<sub>OUT&lt;6dBm</p<sub>	3			mV/dB	
6 <p<sub>OUT&lt;23dBm</p<sub>	8		350	mV/dB	
Current Consumption (I <sub>CC</sub> )					V <sub>CC</sub> =3.3V, V <sub>REG</sub> =3.1V, T=25°C
Quiescent Current		90		mA	RF="0FF" I <sub>CQ</sub> variation from nominal +/- 20mA
11g		170	200	mA	RF P <sub>OUT</sub> =18.5 dBm, 11g, $50 \Omega$
11b		220	290	mA	11Mbps CCK signal, BT=0.45, Rated Output Power, V <sub>CC</sub> =3.3V, Temp=25 °C, $50\Omega$
I <sub>REG</sub>			3	mA	V <sub>REG</sub> >3.0V
V <sub>CC</sub> Leakage Current		2	10	μА	V <sub>CC</sub> =4.8V, V <sub>REG</sub> =C_BT=C_RX=C_BWRX≤0.2V
Input Port Impedance		50		Ω	
Input Port Return Loss	10	15		dB	
Ruggedness					No Damage Conditions: max operating voltage, max input power, max temperature
Output VSWR			10:1		
Input Power			-5	dBm	
Stability					PA must be stable from OdBm to 20dBm. No spurs above -41.25dBm for non-harmonic related signals.
Output VSWR	6:1				CW signal, P <sub>OUT</sub> =20dBm, all phases
Out-of-Band Emissions 2310 MHz to 2390 MHz and 2483.5 MHz to 2500 MHz (FCC restricted bands)			-41.25	dBm/MHz	P <sub>OUT</sub> =16.5dBm, 54Mbps OFDM Modulation, 64QAM, RBW=1MHz, VBW=100kHz, V <sub>CC</sub> =3.3V, V <sub>REG</sub> =3.1V
			-41.25	dBm/MHz	$P_{OUT}$ =20.5 dBm, 11 Mbps CCK Modulation, BT=0.45, RBW=1MHz, VBW=100 kHz, $V_{CC}$ =3.3 V, $V_{REG}$ =3.1 V
Harmonics					11b modulation, 1Mbps, BW=1MHz, up to 3:1 load, P <sub>OUT</sub> =20dBm
Second			-23	dBm	4.80GHz to 5.00GHz
Third			-20	dBm	7.20GHz to 7.50GHz
Turn-on/off Time		0.5	1.0	μS	Output stable to within 90% of final gain, Note 1



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Parameter			Unit	Condition		
2.4 GHz Receive Parameters	_					
Compliance					IEEE802.11b, IEEE802.11g, FCC CFG 15.247,.205,.209, EN, and JDEC	
Frequency	2.4		2.5	GHz		
LNA Voltage Supply (LNA V <sub>CC</sub> )	3.0	3.3	4.2	V	LNA V <sub>CC</sub> can be tied to V <sub>BATT</sub> at all times	
LNA Current		10		mA	LNA in "ON" state	
	0		5	μΑ	LNA in "OFF" state (C_RX=low, LNA V <sub>CC</sub> =ON)	
LNA Input P1dB	-8	-7		dBm		
Gain						
WLAN RX Gain	16	18	20	dB	WLAN RX mode	
Simultaneous WLAN/BT RX Mode	11	13	15	dB	WLAN RX/BT Mode, LNA "ON"	
Noise Figure					V <sub>CC</sub> ≥3.3V, including switch	
WLAN RX		2.1	3.5	dB	WLAN RX mode (LNA "ON")	
Simultaneous WLAN/BT RX Mode		3	4	dB	WLAN RX/BT Mode (LNA "ON")	
Passband Ripple	-0.2		+0.2	dB	WLAN RX Mode	
	-0.5		+0.5	dB	WLAN RX/BT Mode	
WLAN RX Port Return Loss	9.6			dB		
	5			dB	Switch in WLAN RX/Bluetooth Mode	
WLAN RX Port Impedance		50		Ω	No external matching	
Bluetooth Parameters						
Frequency	2.4		2.5	GHz		
Insertion Loss						
BT TX/RX only	4.4	1.2	1.5	dB	Bluetooth mode	
BT/WLAN RX GAIN (simultaneous mode)	11	13	15	dB	WLAN RX/BT Mode, LNA "ON"	
Passband Ripple	-0.2		+0.2	dB	Bluetooth mode	
D.1 . ID	-0.5		+0.5	dB	WLAN RX/BT mode	
Input P1dB	27	30		dB	BT Mode, over temp, C_BT=3.3V to 3.6V	
Bluetooth Port Return Loss	9.6			dB	Switch in Bluetooth Mode	
011 5	7			dB	Switch in WLAN RX/Bluetooth Mode	
Other Requirements						
Antenna Port Impedance						
Output		50		Ω		
Return Loss		10		dB		
Isolation Antonna to Receive	20			4D	In PT Mode (macaused from ANT to DV port)	
Antenna to Receive	20			dB dB	In BT Mode (measured from ANT to RX port)  In TX Mode (measured from ANT to BT port)	
Antenna to Bluetooth®					· · · · · · · · · · · · · · · · · · ·	
Antenna to Receive	20			dB	In TX Mode (measured from ANT to RX port)	
Switch Control Voltage		0	0.2	V	C RX, C BT, and C BW RX control lines  Switch is in the low state (L)	
Low High	1.7	3.3	3.6	V	Switch is in the low state (L)  Switch is in the high state (H)	
Switch Control Current	1.1	2	10	μA	Per control line (C_BT, C_BWRX)	
C_RX Current			100	μА	Over V <sub>CC</sub> , Frequency and Temperature.	
Switch Control Speed			100	nsec	- 1. 100, residency and remperature.	
Switch P1dB		28	100	dBm		
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Parameter	Specification			Unit	Condition	
Farameter	Min.	Тур.	Max.	Ullit	Condition	
Other Requirements,						
continued						
ESD						
Human Body Model	500			V	EIA/JESD22-114A RF pins	
	1000			V	EIA/JESD22-114A DC pins	
Charge Device Model	500			V	JESD22-C101C all pins	

Note 1: The PA module must operate with gated bias voltage input at 1% to 99% duty cycle.

Note 3: Values to be agreed to upon characterization data review: current, gain, return loss, detector sensitivity and output power.

Note 4: The output power for channels 1 and 11 may be reduced to meet FCC restricted band requirements.

### **Switch Control Logic**

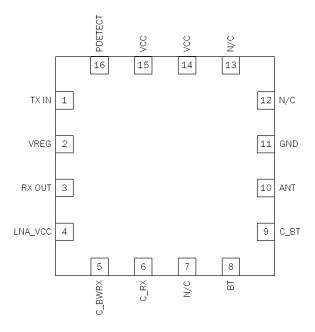
Mode	VREG	C RX	C BT	C BWRx
Standby	L	L	L	L
WLAN TX	Н	L	L	L
WLAN RX	L	Н	L	L
WLAN RX/BT*	L	Н	L	Н
BT RX	L	L	Н	L
BT TX	L	L	Н	L

<sup>\*</sup>The FEM can be placed in receive WLAN and Bluetooth® modes simultaneously with increased insertion loss.

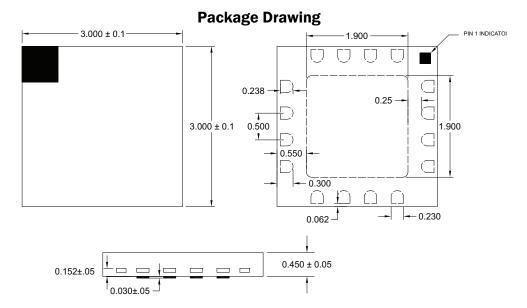


Pin	Function	Description
1	TX_IN	RF input for the 802.11b/g PA. Input is matched to $50\Omega$ and DC block is provided.
2	VREG	Regulated voltage for the bias control circuit, and the TX control port of the SP3T which is also tied to this pin. An external bypass capacitor may be needed on the V <sub>REG</sub> line for decoupling purposes.
3	RX OUT	Receive port for 802.11b/g band. Internally matched to $50\Omega$ . DC block provided.
4	LNA VDD	Voltage supply for the LNA.
5	C_BWRX	SPST switch control pin. (Simultaneous WLAN and BT receive.) See truth table for proper level.
6	C RX	Receive switch control pin. See switch truth table for proper level.
7	N/C	No connect.
8	ВТ	RF bidirectional port for $Bluetooth^{@}$ . Input is matched to $50\Omega$ and DC block is provided.
9	C_BT	Bluetooth® switch control pin. See truth table for proper level.
10	ANT	Port matched to $50\Omega$ and is DC blocked internally.
11	GND	Ground.
12	N/C	No connect.
13	N/C	No connect.
14	vcc	Supply voltage for the PA.
15	vcc	Supply voltage for the bias circuit of the PA.
16	PDETECT	Power detector voltage for TX section. PDET voltage varies with output power. May need external decoupling capacitor for noise bypassing. May need external circuitry to bring output voltage to desired level.

# Pin Out





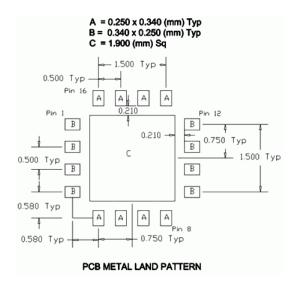


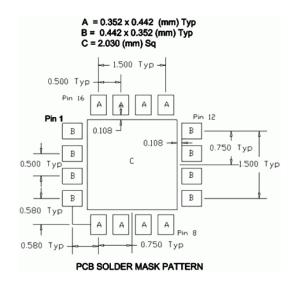
NOTES:

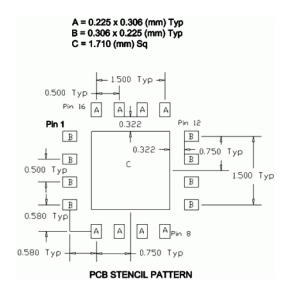
1 Shaded Area is Pin 1 Indicator



# **RF5765 PCB Footprint and Stencil Recommendations**

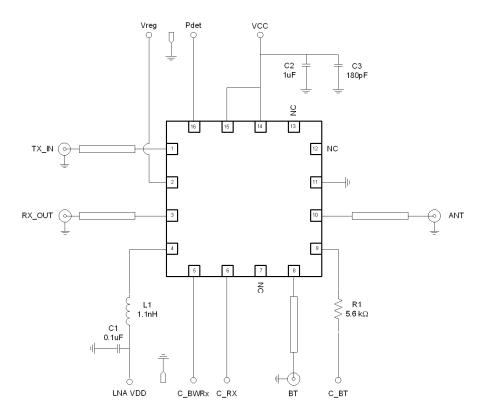








# **Application Schematic**





## **Theory of Operation**

The RF5765 Front End Module (FEM) is designed for WLAN applications in the 2.5 GHz ISM band. It can be applied in many portable applications such as handsets, Portable Media Players, and portable battery power equipment. This highly integrated module can be connected directly to the battery without additional voltage regulators.

### WLAN TRANSMIT MODE

The RF5765 requires a single positive supply ( $V_{CC}$ ), a positive supply for switch controls, and a regulated supply for the  $V_{REG}$  to maintain nominal bias current. The RF5765 transmit path has a typical gain of 30dB from 2.4GHz to 2.5GHz, and delivers 20dBm typical output power under 54Mbps 0FDM modulation and 23dBm under 1Mbps 11b modulation. The RF5765 contains basic filter components to produce a bandpass response for the transmit path. Due to space constraints inside the module, filtering is limited to a few resonant poles and additional filters may be required depending upon the end-user's application. While in transmit mode, the active components are the Power Amplifier (PA) and the TX branch of the SP3T switch. Refer to the logic control table for proper settings.

#### TX Biasing Instructions

- Connect the TX input (pin-1) to a signal generator and a spectrum analyzer at the Antenna output (pin-10)
- Set V<sub>CC</sub> to 3.3V with V<sub>REG</sub> set to 0V
- Turn V<sub>REG</sub> ON and set voltage to 3.1V. V<sub>REG</sub> controls the current drawn by the PA and it should quickly reach a quiescent current of approximately 90 mA±20 mA. Care must be exercised not to exceed 3.5V on the V<sub>REG</sub> pin or the part may be damaged.
- · Control bias to the transmit branch of the SP3T switch is tied directly to V<sub>REG</sub>
- The SP3T controls for the off branches (C\_RX and C\_BT) must be set to a logic "low" (0.2V max) or grounded. In the event
  that one of these branches is left floating or in a logic "high" the performance of the PA will degrade significantly. Likewise,
  unused RF Ports must be terminated in 50Ω to simulate actual system conditions and prevent RF signals from coupling
  back to the PA.
- · Turn RF ON

#### WLAN RECEIVE MODE

Within the frequency band of operation 2.4GHz to 2.5GHz, the RF5765 WLAN receive path has a typical gain of 18dB and a NF of 2.1dB with about 10mA of current. In RX mode, only the RX branch of the SP3T and the LNA are active. Refer to the logic control table for proper settings.

#### **RX Biasing Instructions**

- Connect the RX input (ANT/pin-10) to a signal generator and a spectrum analyzer at the RX output (pin-3). A VNA may be
  used as well.
- Turn the LNA bias ON (pin-4) and set the voltage to 3.3V
- Set C\_RX (pin-6) high. This turns ON the receive branch of the SP3T.
- The SP3T controls for the off branches (V<sub>REG</sub> and C\_BT) must be set to a logic "low" (0.2V max) or grounded. In the event
  that one of these branches is left floating or in a logic "high" the performance will degrade. It is recommended to terminate
  unused RF Ports in 50Ω.
- Set the control bias for the SPST switch (C BWRX/pin-5) "low" during WLAN RX only mode.
- · Turn RF ON



## WLAN and BLUETOOTH® RECEIVE (SIMULTANEOUS MODE)

The RF765 WLAN and *Bluetooth*<sup>®</sup> receive circuits were specifically designed to address issues of simultaneous operation. In this mode both signals can be received at the same time when the C\_BWRX (pin-5) is set high. The typical gain for each RF path is approximately 13dB and a NF of 3dB. During simultaneous mode the active components are the LNA, the SPST switch, and only the RX branch of the SP3T. Refer to the logic control table for proper settings.

#### Simultaneous Mode Biasing Instructions

- Connect the RF input (ANT/pin-10) to a signal generator and a spectrum analyzer at the RX (pin-3) and BT (pin-8) RF ports. A multiport VNA
  may be used as well.
- . Turn the LNA bias ON (pin-4) and set the voltage to 3.3V
- Set C\_RX and C\_BWRX high. This turns ON the receive branch of the SP3T and the SPST switch.
- The SP3T controls for the off branches (V<sub>REG</sub> and C\_BT) must be set to a logic "low" (0.2V max) or grounded. In the event that one of these
  branches is left floating or in a logic "high" the performance will degrade. It is recommended to terminate unused RF Ports in 50Ω.
- Turn RF ON

### BLUETOOTH® MODE

The RF765 Bluetooth® only mode is implemented through the SP3T switch by setting C\_BT "high." Typical insertion loss is about 1.2dB.

## Bluetooth® Biasing Instructions

- Connect the RF input (ANT/pin-10) to a signal generator and a spectrum analyzer at the BT RF port. A VNA may be used in place of the Sig Gen and SA
- Set C\_BT (pin-9) "high." This turns the Bluetooth® branch of the SP3T switch ON.
- The SP3T controls for the off branches (V<sub>RFG</sub> and C\_RX) must be set to a logic "low" (0.2V max) or grounded. Do not leave floating.
- Terminate unused RF Ports in  $50\Omega$
- Turn RF ON

#### APPLICATION CIRCUIT AND LAYOUT RECOMMENDATIONS

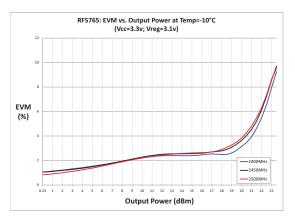
The RF5765 integrates the matching networks and DC blocking capacitors for all RF ports. This greatly reduces the number of external components and layout area needed to implement this FEM. Typically only a total of four external components are required to achieve nominal performance. However, depending on board layout and the many noise signals that could potentially couple to the RF5765, additional bypassing capacitors may be required to properly filter out unwanted signals that might degrade performance.

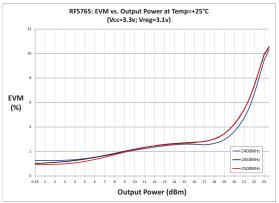
The LNA bias components consist of an inductor and a decoupling capacitor. The inductor value is critical to optimize NF and return loss at the RX output. For best performance and trade off between critical parameters such as NF, Gain, and IP3, the total inductance including board trace should be approximately 1.2 nH. The  $5.6k\Omega$  series resistor for the  $Bluetooth^{@}$  control line helps to prevent unwanted signal from coupling to this pin. The resistor should be place as close as possible to the package pin. The last component needed in the application circuit is a low frequency bypass capacitor on the  $V_{CC}$  line. In general, it is good RF practice to have proper decoupling of supply lines to filter out noise. Occasionally, depending on the level of coupling or parasitics of the board, a high frequency bypass capacitor must be added as well.

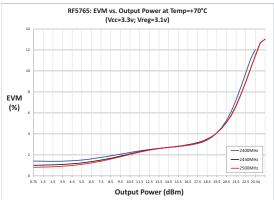
In order to optimize performance for both the Transmit and Receive paths, a good layout design must be implemented. In addition to designing  $50\Omega$  RF lines, proper grounding along the RF traces and on the FEM ground slug must be exercised. This will minimize coupling and provide good thermal dissipation when the PA is operating at high power. For reference, the RFMD evaluation board uses 9 thermal ground vias (hole/capture pad 12/22mil) on the ground slug. Additionally, if space permitted,  $V_{CC}$  and control lines must be isolated from each other with ground vias in between them. RFMD evaluation board gerbers are available upon request.

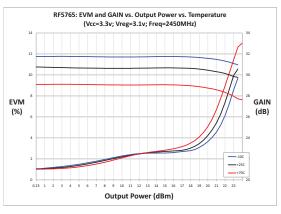


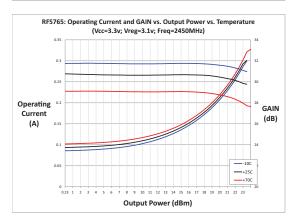
# **RF5765 Transmit Performance Graphs**

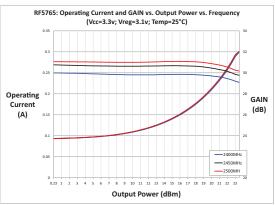






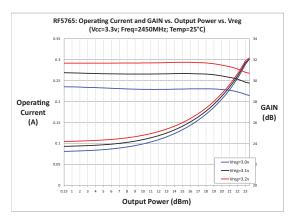


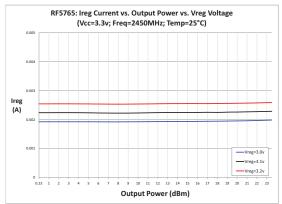


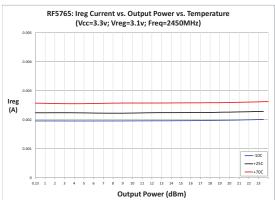


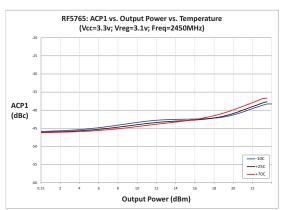


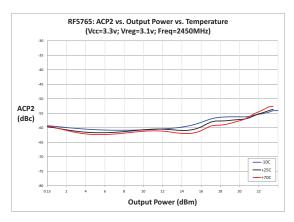
# **RF5765 Transmit Performance Graphs (continued)**





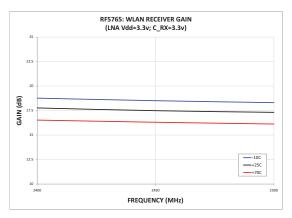


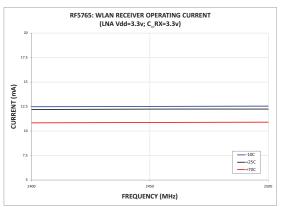


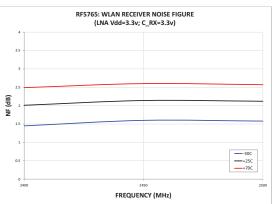




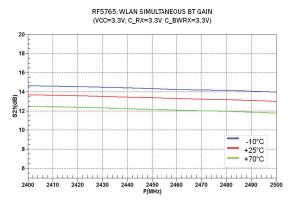
## **RF5765 Receive Performance Graphs**

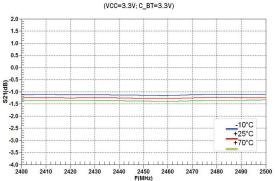












RF5765: BLUETOOTH INSERTION LOSS